Chapter 5 - Reading Assignments

ECE 8853 “Silicon-Based Heterostructure Devices and Circuits”
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Articles:


Reference Material:


Textbook:


Chapter 5 Second Order Effects

5.1 Ge Grading issues C 4.3
5.2 neutral base recombination C 4.3
5.3 barrier effects C 4.3

More Advanced Material (Optional):

